### **DESCRIPTION**

The SPN2308 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

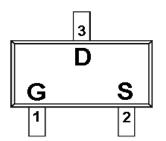
### **FEATURES**

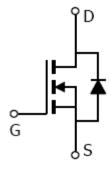
- 20V/2.0A,RDS(ON)= $380m\Omega$ @VGS=4.5V
- 20V/1.5A,RDS(ON)= $450m\Omega$ @VGS=2.5V
- 20V/1.0A,RDS(ON)=800m $\Omega$ @VGS=1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-23-3L package design

### **APPLICATIONS**

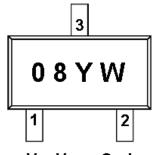
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

## PIN CONFIGURATION (SOT-23-3L)





### **PART MARKING**



Y: Year Code W: Week Code

PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

## **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN2308S23RGB	SOT-23-3L	08

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

 $\begin{tabular}{ll} $\$ SPN2308S23RGB: Tape\ Reel\ ;\ Pb-Free\ ;\ Halogen-Free \end{tabular}$ 

## ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

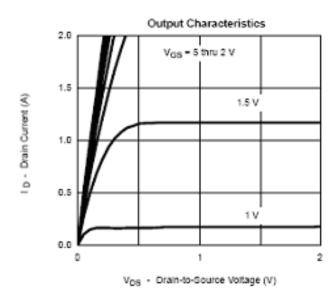
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Dusin Comment/Tr-1509C	Ta=25°C	In	2.0	Δ.	
Continuous Drain Current(T <sub>J</sub> =150°C)	Ta=70°C	- Id	1.5	A	
Pulsed Drain Current		IDM	10	A	
Continuous Source Current(Diode Conduction)		Is	1.6	A	
Decree Discipation	Ta=25°C	PD	1.25	W	
Power Dissipation	Ta=70°C		0.8	W	
Operating Junction Temperature		Tı	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	105	°C/W	

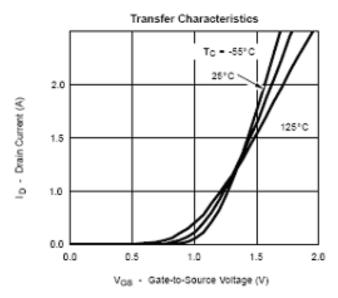
## **ELECTRICAL CHARACTERISTICS**

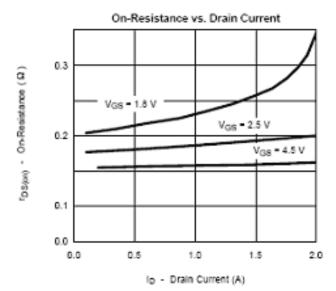
(Ta=25°C Unless otherwise noted)

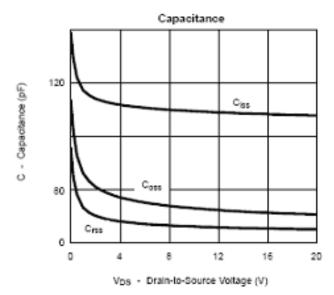
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,Id= 250uA	20			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.35		1.0	\ \
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			100	nA
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 20V,V <sub>GS</sub> =0V V <sub>DS</sub> = 20V,V <sub>GS</sub> =0V T <sub>J</sub> =55°C			5	uA
On-State Drain Current	ID(on)	V <sub>DS</sub> ≥ 4.5V,V <sub>GS</sub> =5V	2			A
Drain-Source On-Resistance	RDS(on)	VGS=4.5V,ID=2.0A VGS=2.5V,ID=1.5A VGS=1.8V,ID=1.0A		0.15 0.21 0.32	0.38 0.45 0.80	Ω
Forward Transconductance	gfs	Vds=10V,Id=1.2A		2.6		S
Diode Forward Voltage	Vsd	Is=0.5A,VGS=0V		0.8	1.2	V
Dynamic			•			
Total Gate Charge	Qg	VDS=10V,VGS=4.5V, ID=0.7A		1.2	1.5	nC
Gate-Source Charge	Qgs			0.2		
Gate-Drain Charge	Qgd			0.3		
Input Capacitance	Ciss			110		pF
Output Capacitance	Coss	VDS=10VGS=0V f=1MHz		34		
Reverse Transfer Capacitance	Crss			16		
Turn-On Time	td(on)	$V_{DD}=10V,R_{L}=10\Omega$ , $I_{D}=1.0A$		5	10	
	tr			8	15	
	td(off)	$V_{GEN}=4.5V$ , $R_{G}=6\Omega$		10	18	nS
Turn-Off Time	tf			1.2	2.8	7

## TYPICAL CHARACTERISTICS

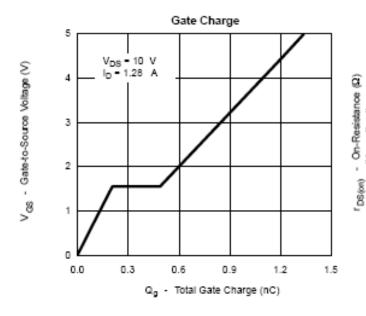


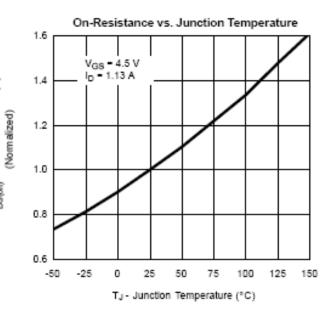


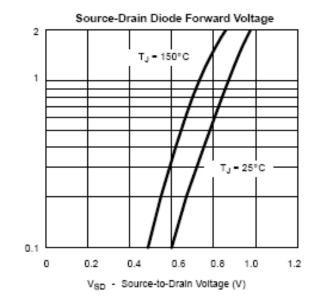




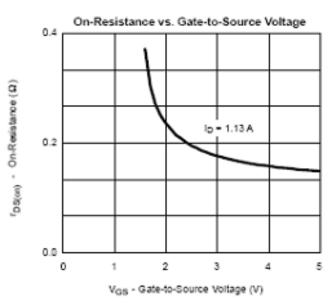
## TYPICAL CHARACTERISTICS



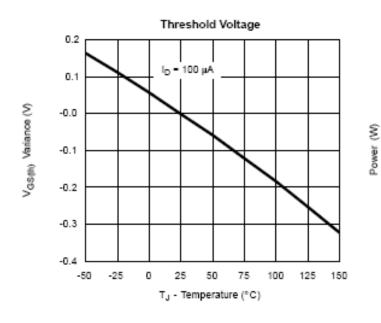


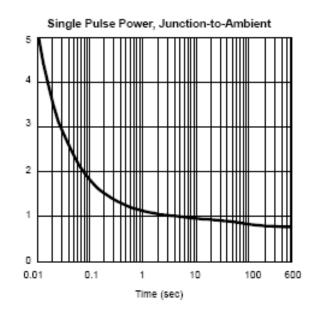


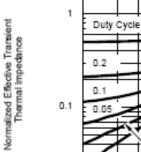
Is - Source Current (A)

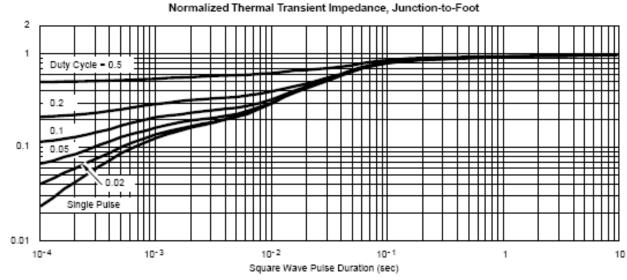


# TYPICAL CHARACTERISTICS









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